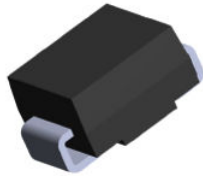


Thyristor surge suppressor (TSS)



SMB
(JEDEC DO-214AA)



Product status link

[SMP100MC](#)

Features

- Bidirectional crowbar protection
- Voltage: range from 140 V to 400 V
- Low V_{BO} / V_R ratio
- Micro capacitance from 15 pF to 30 pF at 50 V
- Low leakage current: $I_R = 2 \mu\text{A}$ max
- Holding current: $I_H = 150 \text{ mA}$ min.
- Repetitive peak pulse current:
 - $I_{PP} = 100 \text{ A}$ (10/1000 μs)
- **Benefits:**
 - TSS (Thyristor surge suppressor) are not subject to ageing and provide a fail safe mode in short circuit for better protection
 - Helps equipment meet main standards such as UL60950, IEC 950 / CSA C22.2 and UL1459
 - Epoxy meets UL94, V0
 - Package is JEDEC registered (DO-214AA)
- **Complies with the following standards:**
 - IEC 61000-4-5
 - IEC 61000-4-2 level 4
 - GR-1089 Core
 - ITU-T-K20/K21
 - TIA/EIA IS-968
 - UL497B recognized, UL file E136224

Applications

These devices protect sensitive equipment from lightning strikes and AC power faults. They are designed for industrial and telecom applications because they comply with the most stringent standards. Their low capacitance makes them suitable for data line protection.

- Terminals (phone, fax, modem...) and central office equipment
- ADSL2+ and low end VDSL

Description

The SMP100MC series consists of micro-capacitance transient surge arresters designed to protect high data rate communication equipment. The micro-capacitance prevents signal distortion and is compatible with digital transmission line cards, such as ADSL, VDSL, and Ethernet.

1 Characteristics

Table 1. In compliance with the following standards

Standard	Peak surge voltage (V)	Waveform voltage	Required peak current (A)	Current waveform	Minimum serial resistor to meet standard (Ω)
GR-1089 Core First level	2500	2/10 μ s	500	2/10 μ s	0
	1000	10/1000 μ s	100	10/1000 μ s	0
GR-1089 Core Second level	5000	2/10 μ s	500	2/10 μ s	0
GR-1089 Core Intra-building	1500	2/10 μ s	100	2/10 μ s	0
ITU-T-K20/K21	6000	10/700 μ s	150	5/310 μ s	0
	1500		37.5		0
ITU-T-K20 (IEC61000-4-2)	8000	1/60 ns	ESD contact discharge		0
	15000		ESD air discharge		0
IEC61000-4-5	4000	10/700 μ s	100	5/310 μ s	0
	4000	1.2/50 μ s	100	8/20 μ s	0
TIA/EIA IS-968, lightning surge type A	1500	10/160 μ s	200	10/160 μ s	0
	800	10/560 μ s	100	10/560 μ s	0
TIA/EIA IS-968, lightning surge type B	1000	9/720 μ s	25	5/320 μ s	0

Table 2. Absolute ratings ($T_{amb} = 25\text{ }^{\circ}\text{C}$)

Symbol	Parameter	Value	Unit	
I_{PP}	Repetitive peak pulse current	10/1000 μs	100	A
		8/20 μs	300	
		10/560 μs	140	
		5/310 μs	150	
		10/160 μs	200	
		1/20 μs	300	
		2/10 μs	500	
I_{FS}	Fail-safe mode: maximum current ⁽¹⁾	8/20 μs	5	kA
I_{FS}	Non repetitive surge peak on-state current (sinusoidal)	t = 0.2 s	18	A
		t = 1 s	9	
		t = 2 s	7	
		t = 15 mn	4	
I^2t	I^2t value for fusing	t = 16.6 ms	20	A^2s
		t = 20 ms	21	
T_{stg}	Storage temperature range	-55 to +150	$^{\circ}\text{C}$	
T_j	Operating junction temperature range	-40 to +150	$^{\circ}\text{C}$	
T_L	Maximum lead temperature for soldering during 10 s	260	$^{\circ}\text{C}$	

1. In fail safe mode the device acts as a short circuit.

Table 3. Thermal resistance parameter

Symbol	Parameter	Typ. value	Unit
$R_{th(j-a)}$	Junction to ambient (with recommended footprint)	100	$^{\circ}\text{C}/\text{W}$
$R_{th(j-l)}$	Junction to leads	20	

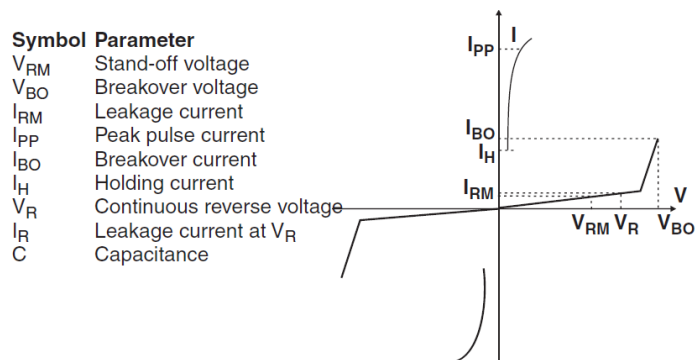
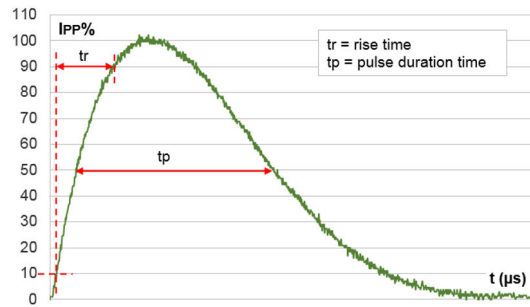
Figure 1. Electrical characteristics - parameter definitions


Figure 2. Pulse definition for electrical characteristics

Table 4. Electrical characteristics - parameter values ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

Type	I_{RM} max at V_{RM}		I_R at V_R		Dynamic V_{BO} (1)	Static V_{BO} at I_{BO} (2)		I_H (3)	C (4)	C (5)
	Max.		Max.		Max.	Max.	Max.	Min.	Typ.	Typ
	μA	V	μA	V	V	V	mA	mA	pF	pF
SMP100MC-140	2	126	5	140	180	175	800	150	30	60
SMP100MC-160		144		160	205	200			25	50
SMP100MC-200		180		200	255	250			20	45
SMP100MC-270		243		270	345	335			20	40
SMP100MC-400		360		400	540	530			15	30

1. See Figure 10.
2. See Figure 11.
3. See Figure 12.
4. $V_R = 50\text{ V bias}$, $V_{RMS} = 1\text{ V}$, $F = 1\text{ MHz}$.
5. $V_R = 2\text{ V bias}$, $V = 1\text{ V}$, $F = 1\text{ MHz}$.

1.1 Characteristics (curves)

Figure 3. Non repetitive surge peak on-state current versus overload duration

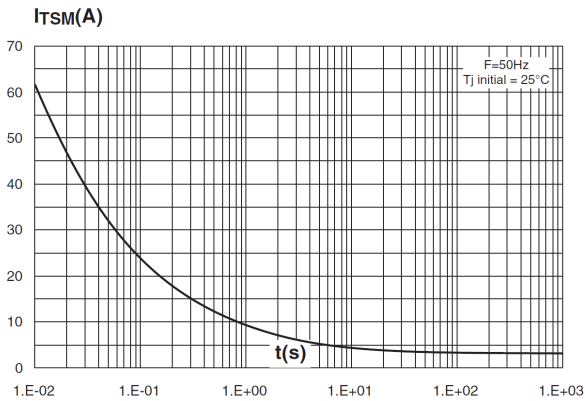


Figure 4. On-state voltage versus on-state current (typical values)

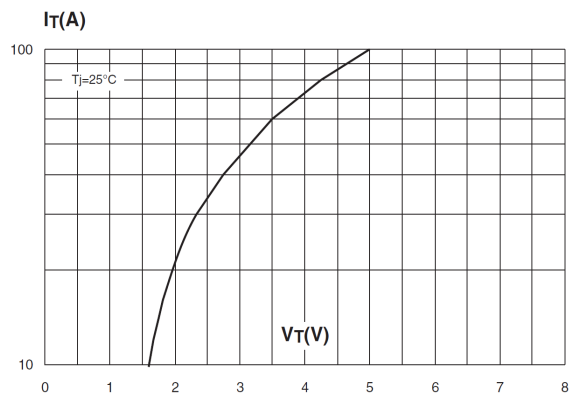


Figure 5. Relative variation of holding current versus junction temperature

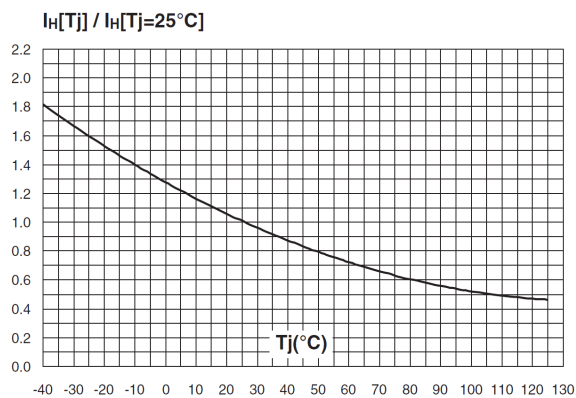


Figure 6. Relative variation of breakover voltage versus junction temperature

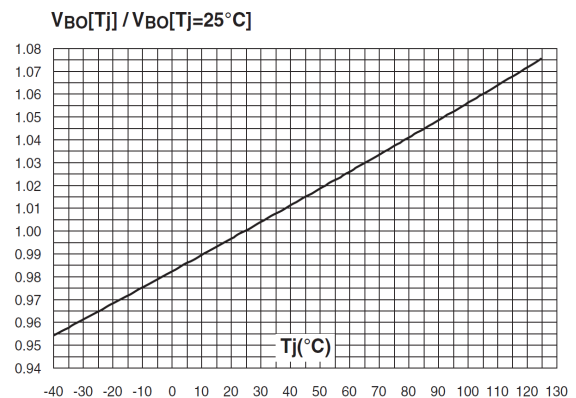


Figure 7. Relative variation of leakage current versus reverse voltage applied (typical values)

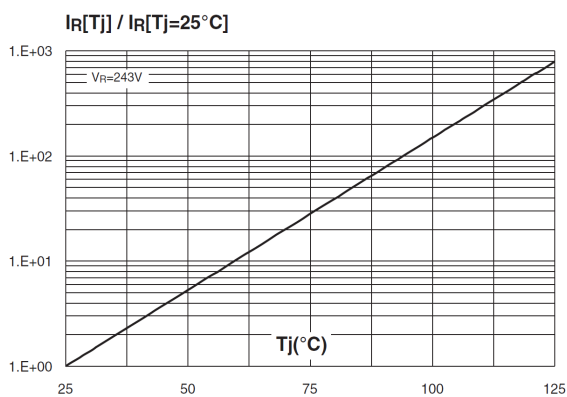


Figure 8. Variation of thermal impedance junction to ambient versus pulse duration

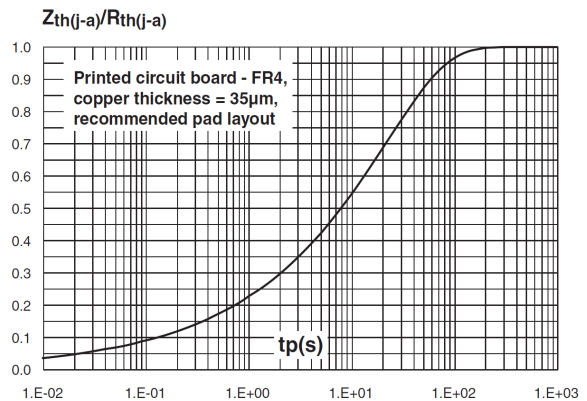
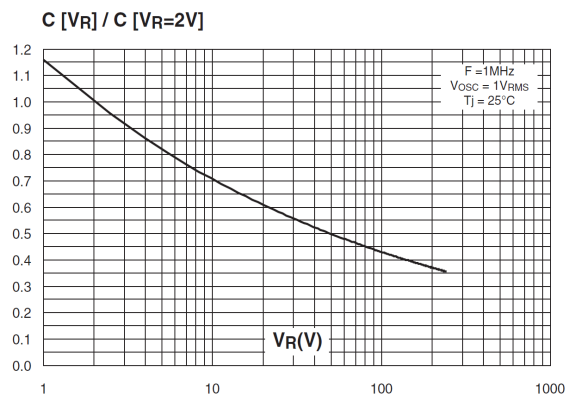


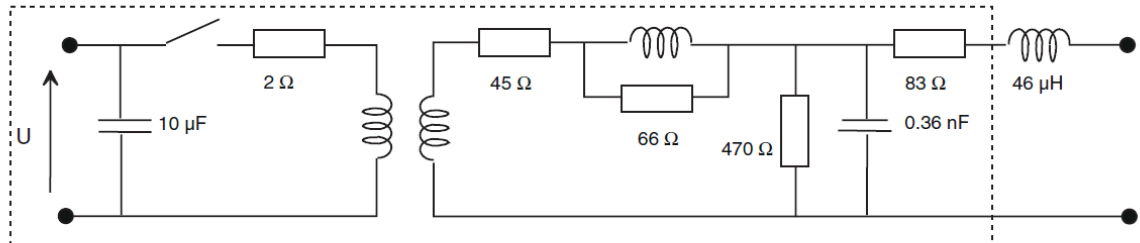
Figure 9. Relative variation of junction capacitance versus reverse voltage applied (typical values)



2 Measurement setups

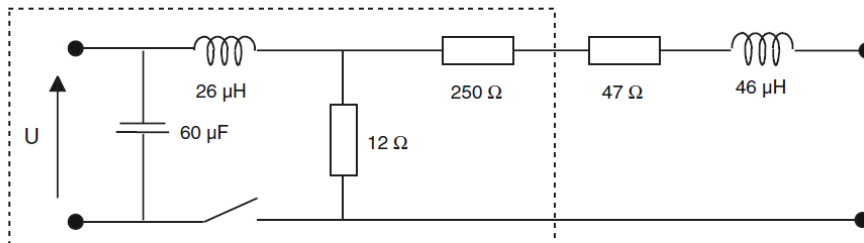
Figure 10. Test circuit 1 for Dynamic I_{BO} and V_{BO} parameters

$100\text{ V} / \mu\text{s}$, $di/dt < 10\text{ A} / \mu\text{s}$, $I_{pp} = 100\text{ A}$



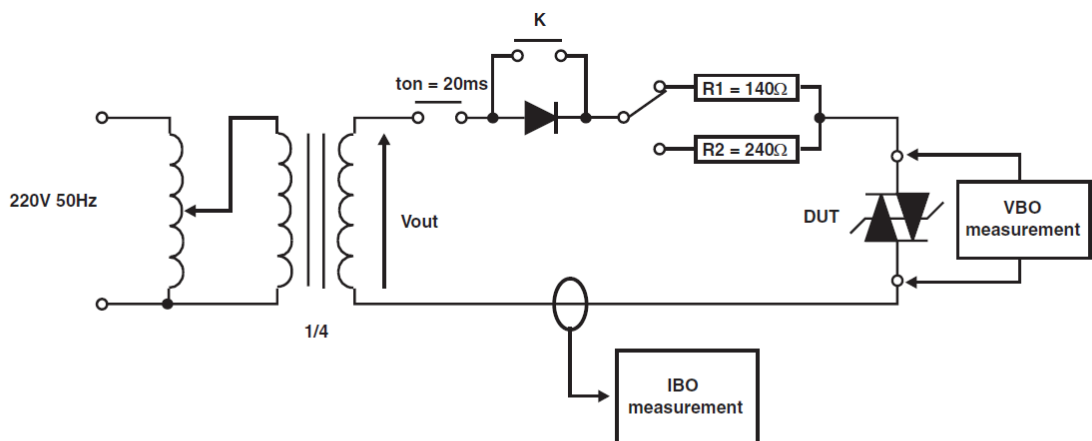
KeyTek 'System 2' generator with PN2461 module

$1\text{ kV} / \mu\text{s}$, $di/dt < 10\text{ A} / \mu\text{s}$, $I_{pp} = 10\text{ A}$



KeyTek 'System 2' generator with PN2461 module

Figure 11. Test circuit 2 for I_{BO} and V_{BO} parameters



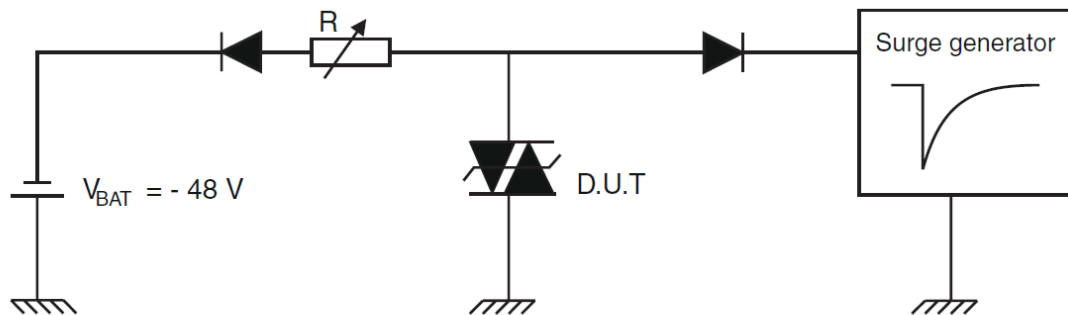
TEST PROCEDURE

Pulse test duration ($t_p = 20\text{ms}$):

- for Bidirectional devices = Switch K is closed
- for Unidirectional devices = Switch K is open

V_{OUT} selection:

- Device with $V_{BO} < 200\text{ V}$ → $V_{OUT} = 250\text{ V}_{RMS}$, $R1 = 140\ \Omega$
- Device with $V_{BO} \geq 200\text{ V}$ → $V_{OUT} = 480\text{ V}_{RMS}$, $R2 = 240\ \Omega$

Figure 12. Test circuit 3 for dynamic I_H parameter


This is a GO-NOGO test which allows to confirm the holding current (I_H) level in a functional test circuit.

TEST PROCEDURE

- 1/ Adjust the current level at the I_H value by short circuiting the AK of the D.U.T.
- 2/ Fire the D.U.T. with a surge current $\rightarrow I_{PP} = 10 \text{ A}, 10/1000 \mu\text{s}$.
- 3/ The D.U.T. will come back off-state within 50 ms maximum.

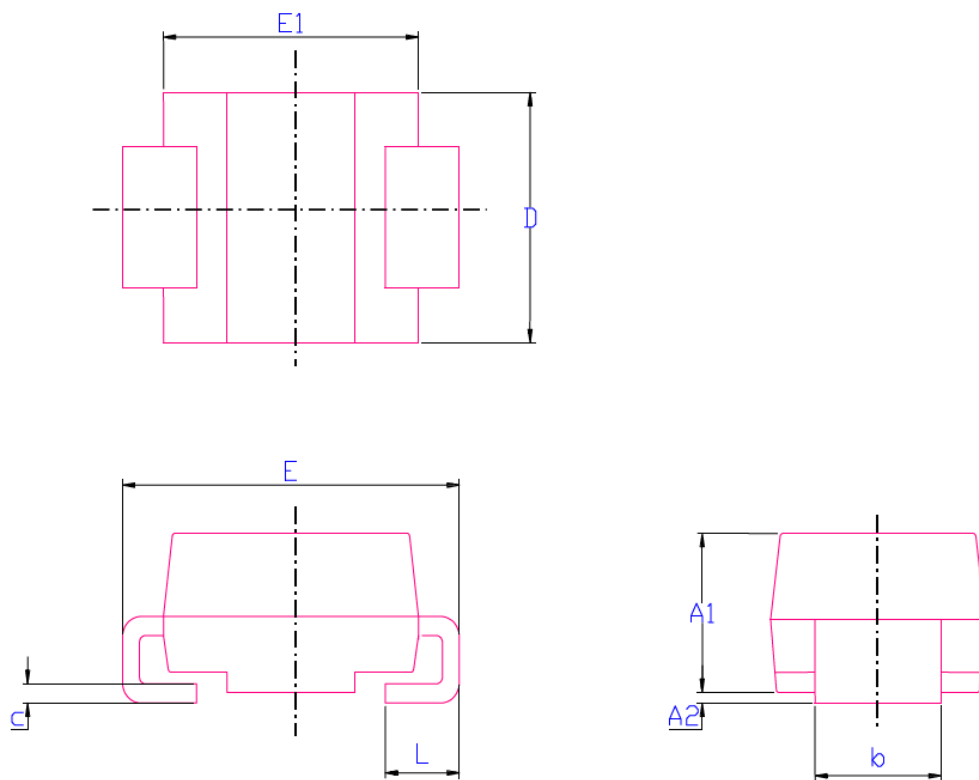
3 Package information

To meet environmental requirements, ST offers these devices in different grades of **ECOPACK** packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions, and product status are available at: www.st.com. ECOPACK is an ST trademark.

3.1 SMB package information

- Epoxy meets UL94, V0
- Lead free plating + halogen-free molding resin

Figure 13. SMB package outline



0087334_1_18

Table 5. SMB package mechanical data

Ref.	Dimensions					
	Millimeters			Inches ⁽¹⁾		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A1	1.90		2.45	0.075		0.096
A2	0.05		0.20	0.002		0.008
b	1.95		2.20	0.077		0.087
c	0.15		0.40	0.006		0.016
D	3.30		3.95	0.130		0.156
E	5.10		5.60	0.201		0.220
E1	4.05		4.60	0.159		0.181
L	0.75		1.50	0.030		0.059

1. Inches only for reference

Figure 14. SMB footprint

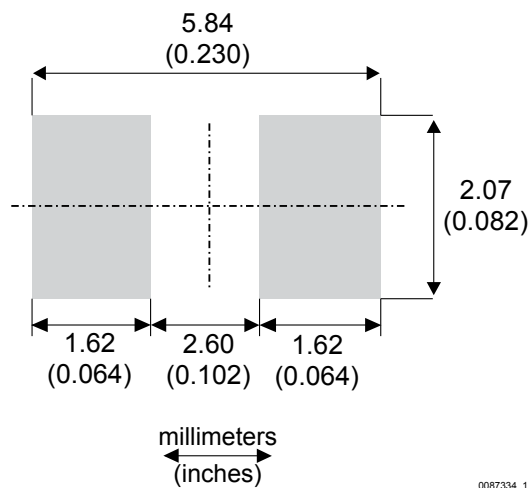
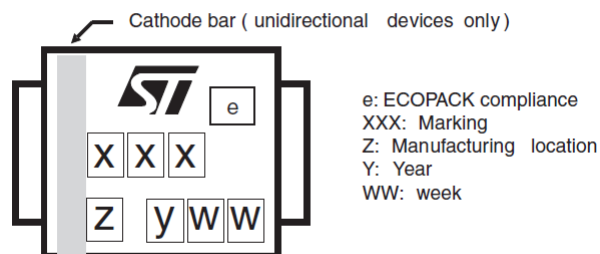


Figure 15. Marking layout



Note: Marking layout can vary according to assembly location.

4 Ordering information

Figure 16. Ordering information scheme

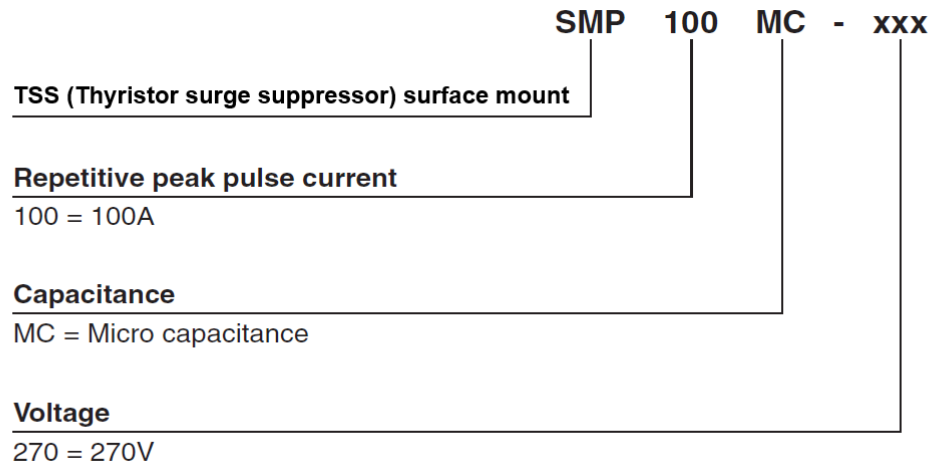


Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
SMP100MC-140	ML14	SMB	98 mg	2500	Tape and reel
SMP100MC-160	ML16				
SMP100MC-200	ML20				
SMP100MC-270	ML27				
SMP100MC-400	ML40				

Revision history

Table 7. Document revision history

Date	Version	Changes
September-2003	0B	First issue.
14-Dec-2004	1	Absolute ratings values, <i>table 3</i> on page 2, updated.
11-May-2005	2	New types introduction.
20-Jun-2005	3	Telecom Circuit Protector added
05-Jan-2006	4	SMP100MC-320 / 360 / 400 in full production ("in development" mention removed)
09-Feb-2012	5	Added UL statement in Complies with the following standards.
11-Mar-2026	6	Updated Table 4 , Section 3.1: SMB package information , and Table 6 . Minor texte changes.

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